



Fatima Khelfaoui

Lecturer searcher

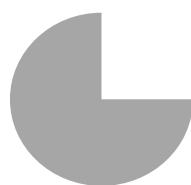
PROFIL



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LANGUES

Arabe



French



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FORMATION

1996

Constantine , Algeria

State engineer in electronic

Frères Mentouri university

2000

Constantine , Algeria

Magister in electronic

Frères Mentouri university

2014

Constantine , Algeria

Doctorate in science in physics (sciences of materials)

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- **F.Khelfaoui**, M. Remram,'Fonctionnement d'une cellule solaire à base du silicium multicristallin à haute température', revue des énergies renouvelables numéro spécial ISSN 1112-2242 Mai 2000.
- **F.Khelfaoui** and M.S. Aida, 'Substrat-plasma interaction during amorphous silicon thin films growth by sputtering technique', Eur.Phys. J. Appl. Phys. 47, 31001 (2009).
- **F.Khelfaoui** and M.S. Aida, 'Films Surface temperature calculation during growth by sputtering technique ', Journal Of Semiconductor 38(9) Sep (2017).
- Itidal Belaidi, **Fatima Khelfaoui**, Nadhir Attaf, Assia Azzizi, and Mohammed Salah Aida, 'Solvent and Spinning Speed Effects on $\text{CH}_3\text{NH}_3\text{PbI}_3$ Films Deposited by Spin Coating' Phys. Status Solidi A 2019, 1900340
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